

Positive Fixed 5V Voltage Regulator in bare die form

Rev 1.0 19/04/19

Description

The 7805 5V fixed 3-terminal positive voltage regulator delivers up to 1.5A of output current with adequate heat-sinking. The device is equipped with internal limiting, safe-area compensation + thermal shutdown features for overload immunity. The 7805 can be used with external components to obtain adjustable voltages or currents & can also be used as the power-pass element in precision high-current voltage regulators. No external components are needed other than to enhance performance or increase design flexibility.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection
 + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K_AT

LAT = Lot Acceptance Test.

For further information on LAT places flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

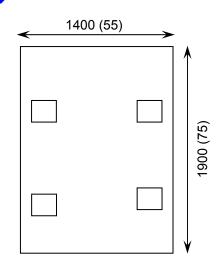
Supply Formats:

- Defaut Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Tape & Reel On request
- In Metal or Ceramic package On request

Features:

- ±5% V_{OUT} tolerance over entire temperature range
- Greater than 1A output current capability
- Internal thermal overload procession
- Internal short-circuit current limit
- Output capacitor not essential for stability
- Full Military temperature range
- Negative oltage complement is 7905

Die Din ensions in µm (mils)



Mechanical Specification

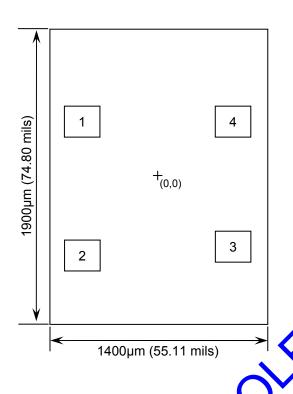
Die Size (Unsawn)	1400 x1900 55 x 75	μm mils	
Minimum Bond Pad Size	230 x 230 9.05 x 9.05	μm mils	
Die Thickness	280 (±20) 11.02 (±0.79)	μm mils	
Top Metal Composition	Al 1%Si 1.1μm		
Back Metal Composition	Ti/Ni/Ag 1.2 μm		





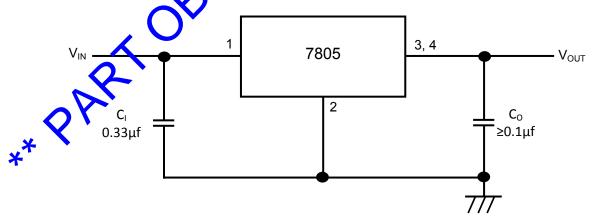
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Pad Layout and Functions



PAD	FUNCTION	COORDINATES (µm)		
ואס	1 ONO HON	X	Y	
1	V _{IN}	-610	247	
2	GNV	-610	-626	
3	V _{OU}	372	-560	
4	V _{OUT}	372	247	
	CONNECT CHI	P BACK TO	GND	

Typical Application



 $C_{\rm l}$ is required if the regulator is located an appreciable distance from power supply filter. $C_{\rm O}$ is not required for stability; however it does improve transient response. For optimum stability and transient response locate $C_{\rm l}$ $C_{\rm O}$ as close as possible to the regulator. A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.





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Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UN'I	
Input Voltage	V _{IN}	36	V	
Power Dissipation ¹	P _D	Internally Limited	V	
Operating Temperature Range	-	-55 to 150	°C	
Maximum Junction Temperature	T _J	150	°C	
Storage Temperature	T _{STG}	-65 to 150	°C	

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	V _{IN}		25	V
Output Current	I _{OUT}		1.5	A
Operating Temperature Range	T _J	-55	125	°C

DC Electrical Characteristics, V_I =10V, I_{OUT}=50 A, C_I=0.33 µF, C_O=0.1 µf, T_{MIN}≤T_J≤T_{MAX}(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Voltage	V _{OUT}	TJ = 25°C	4.80	5.00	5.20	
		5m/ ≤ l ₀ ≤ 1A, 7V ≤ V _N ≤ 20V, P _D ≤ 15 Watts	4.75	5.00	5.25	V
Line Regulation	ΔV _{OUT}	.5У ≤ V _{IN} ≤ 20V	-	0.5	20	mV
Line Regulation	A V OUT	8V ≤ V _{IN} ≤ 12V	-	0.8	10	
Load Regulation	ΔV _{OUT}	5mA ≤ I _{OUT} ≤ 1A	-	1.3	25	
Load Regulation		$5\text{mA} \le I_{\text{OUT}} \le 1.5\text{A}, T_{\text{J}} = 25^{\circ}\text{C}$	-	1.3	25	
Input Bias Current	IB		-	3.2	6.5	mA
Input Bias Current	ΔI_{B}	7.5V ≤ V _{IN} ≤ 25V	-	0.3	1	mA
Change	ΔiB	$5\text{mA} \le I_{\text{OUT}} \le 1\text{A}, T_{\text{J}} = 25^{\circ}\text{C}$	-	0.08	0.8	110.0
Output Noise Voltage	V _n	10Hz ≤ f ≤ 100KHz, T _J = 25°C	-	10	-	μV/V _{OUT}
Ripple Rejection	RR	$8V \le V_{IN} \le 18V$, f = 120Hz,	-	68	-	dB
Dropout Yoltage	$V_{IN} - V_{OUT}$	$I_{OUT} = 1A, T_{J} = 25^{\circ}C$	-	2	-	V
Output Registance	r _{OUT}	f = 1 kHz	-	0.9	-	mΩ
Short-Circuit Current Limit	I _{SC}	V _{IN} = 35V, T _A = 25°C	-	0.6	-	А
Peak Output Current	I _{MAX}	T _J = 25°C	-	2.2	-	Α
Avg. Output Voltage Temp. Coefficient	TCV _{OUT}		-	-0.3	-	mV/°C

^{1.} Results in die form are dependent on die attach and assembly method. Max power dissipation is internally limited by the die.





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Typical Characteristics

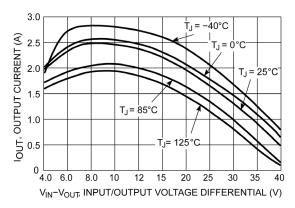


Figure 1 – Peak output current as a function of input/output differential voltage

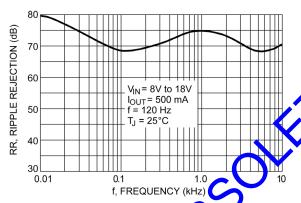


Figure 3 – Ripple rejection as a function of frequency

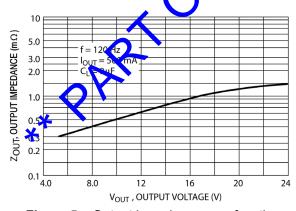


Figure 5 – Output impedance as a function of output Voltage

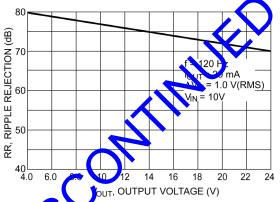


Figure 2 – Ripple rejection as a function of output voltage

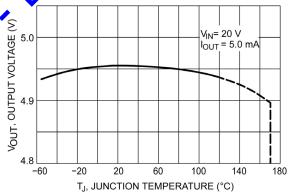


Figure 4 – Output voltage as a function of junction temperature

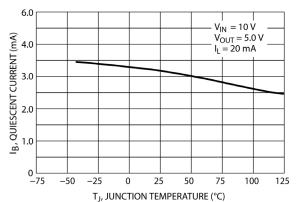


Figure 6 – Quiescent current as a function of temperature





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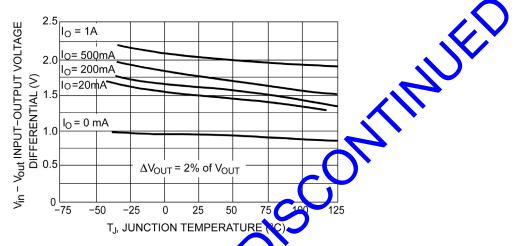
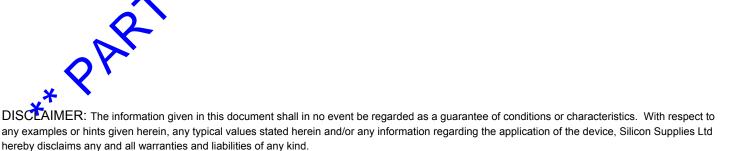


Figure 7 – Quiescent current as a function of temperature



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